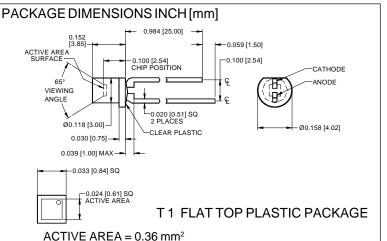
PHOTONIC Si DETECTORS INC.



Silicon Photodiode, Blue Enhanced Photoconductive Type PDB-C130, with daylight filter Type PDB-C130F



FEATURES

- Photoconductive
- High speed
- Low cost
- Flat top, T1 package

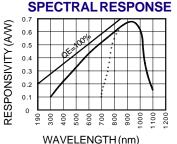
DESCRIPTION: The **PDB-C130** detector is a 0.36 mm² planar pin photodiode packaged in a T1 flat top, water clear plastic housing. Designed for high speed, low capacitance, photoconductive applications. The **PDB-C130F** includes a daylight filter.

APPLICATIONS

- Smoke detectors
- Light pen detectors
- TV & VCR remotes
- IRDA sensor

ABSOLUTE MAXIMUM RATING (TA=25°C unless otherwise noted)

SYMBOL	PARAMETER	MIN	MAX	UNITS	
V _{BR}	Reverse Voltage		100	V	
T _{stg}	Storage Temperature	-40	+100	°C	
T _o	Operating Temperature Range	-40	+80	°C	
T _s	Soldering Temperature*		+260	°C	
Ι	Light Current		0.5	mA	



*1/16 inch from case for 3 secs max

ELECTRO-OPTICAL CHARACTERISTICS (TA=25°C unless otherwise noted)

SYMBOL	CHARACTERISTIC	TESTCONDITIONS	MIN	TYP	MAX	UNITS
I _{sc}	Short Circuit Current	H = 100 fc, 2850 K	4	5		μ A
I _D	Dark Current	H = 0, V _R = 10 V		1	5	nA
R _{SH}	Shunt Resistance	H = 0, V _R = 10 mV	.5	5		GΩ
TCR _{SH}	RSH Temp. Coefficient	H = 0, V _R = 10 mV		-8		% / °C
C	Junction Capacitance	H = 0, V _R = 10 V*		2	5	pF
λrange	Spectral Application Range	(without daylight filter)**	400		1100	nm
λρ	Spectral Response - Peak			950		nm
V _{BR}	Breakdown Voltage	I = 10 μA	50	100		V
NEP	Noise Equivalent Power	V _R = 10 V @ Peak		6.0x10 ⁻¹⁵		W/ √ Hz
tr	Response Time	$RL = 1 K\Omega V_R = 10 V$		5		nS

Information in this technical data sheet is believed to be correct and reliable. However, no responsibility is assumed for possible inaccuracies or omission. Specifications are subject to change without notice: *f = 1 MHz, ** daylight filter=700 - 1100 nm [FORM NO. 100-PDB-C130 REV A]